TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

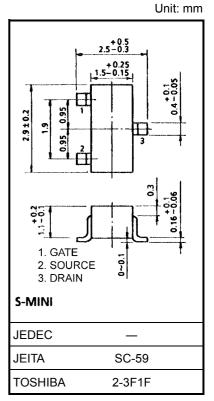
## 2SK1062

# High Speed Switching Applications Analog Switching Applications Interface Applications

- Excellent switching time: ton = 14 ns (typ.)
- High forward transfer admittance:  $|Y_{fs}| = 100 \text{ mS (min)}$ 
  - $@I_D = 50 \text{ mA}$
- Low on resistance:  $RDS(ON) = 0.6 \Omega \text{ (typ.)} @ ID = 50 \text{ mA}$
- Enhancement-mode
- Complementary to 2SJ168

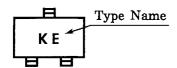
#### **Maximum Ratings (Ta = 25°C)**

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		V <sub>DS</sub>	60	V	
Gate-source voltage		V <sub>GSS</sub>	±20	V	
Drain current	DC	I <sub>D</sub>	200	mA	
	Pulse	I <sub>DP</sub>	800		
Drain power dissipation (Ta = 25°C)		PD	200	mW	
Channel temperature		T <sub>ch</sub>	150	°C	
Storage temperature range		T <sub>stg</sub>	-55~150	°C	



Weight: 0.012 g (typ.)

#### Marking



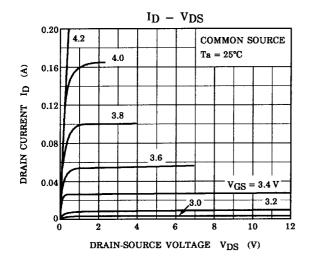


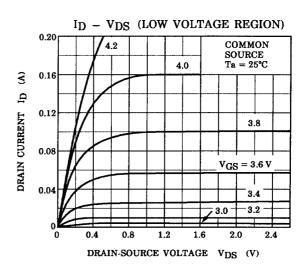
### Electrical Characteristics (Ta = 25°C)

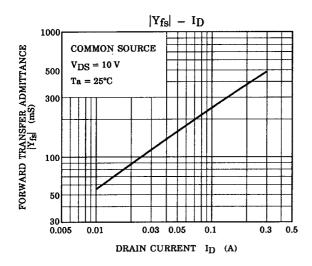
Charac	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage curre	ent	I <sub>GSS</sub>	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0$	_	_	±100	nA
Drain cut-off curre	nt	I <sub>DSS</sub>	V <sub>DS</sub> = 60 V, V <sub>GS</sub> = 0	_	_	10	μΑ
Drain-source brea	kdown voltage	V (BR) DSS	I <sub>D</sub> = 1 mA, V <sub>GS</sub> = 0	60	_	_	V
Gate threshold vol	tage	V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	2	_	3.5	V
Forward transfer a	dmittance	Y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 50 mA	100	_	_	mS
Drain-source ON r	esistance	R <sub>DS (ON)</sub>	$I_D = 50 \text{ mA}, V_{GS} = 10 \text{ V}$	_	0.6	1.0	Ω
Drain-source ON v	/oltage	V <sub>DS (ON)</sub>	$I_D = 50 \text{ mA}, V_{GS} = 10 \text{ V}$	_	30	50	mV
Input capacitance		C <sub>iss</sub>	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0, f = 1 MHz	_	55	65	pF
Reverse transfer capacitance		C <sub>rss</sub>	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0, f = 1 MHz	_	13	18	pF
Output capacitance		Coss	$V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	40	50	pF
Switching time	Rise time	t <sub>r</sub>	$I_{D} = 100 \text{ mA}$ $V_{IN} = 100 \text{ mA}$ $V_{DD} = 30 \text{ V}$ $V_{IN}: t_{r}, t_{f} < 5 \text{ ns}$ $D.U \le 1\% (Z_{out} = 50 \Omega)$	_	8	_	ns
	Turn-on time	t <sub>on</sub>		_	14	_	
	Fall time	t <sub>f</sub>		_	35	_	
	Turn-off Time	t <sub>off</sub>		_	75		

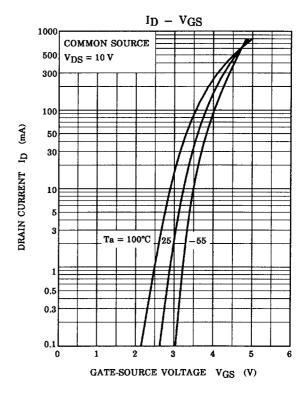
Note: This transistor is the electrostatic sensitive device. Please handle with caution.

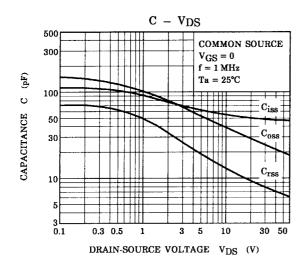
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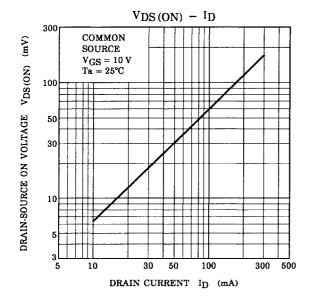


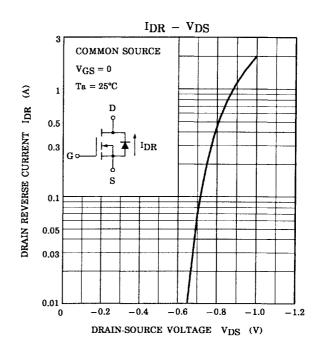


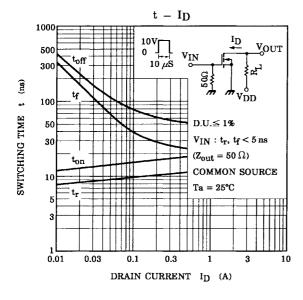


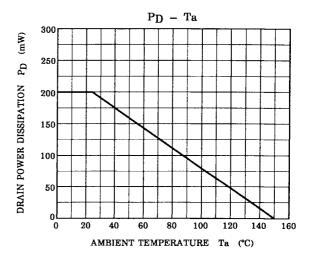


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